Intel highlights new technology being developed at its Rio Rancho plant

Sep 26, 2019



Rob Crooke, Intel senior vice president and general manager of Non-Volatile Memory Solutions Group, shares Intel's vision and strategy in Memory and Storage to global press at the Intel Memory/Storage day on Thursday in Seoul, South Korea.

Courtesy Intel Corp.

On stage in Seoul, South Korea, Intel Corp. [NASDAQ: INTC] announced Thursday milestones and investments in advance memory and storage technology developed at its Rio Rancho plant.

Intel said it plans to operate a new Optane technology development line at its <u>facilities in Rio Rancho</u>. Optane is a new advanced memory technology designed to speed moving data between memory and a central or main processor, boosting performance for the user, <u>according to sister publication</u>

<u>Portland Business Journal</u>. The Santa Clara, California-based tech giant said the new technology offers solutions for cloud, artificial intelligence and network edge applications.

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"The world is generating data at an accelerating rate, and businesses are increasingly becoming overwhelmed with how to efficiently process it," said Rob Crooke, Intel senior vice president and general manager of the Non-Volatile Memory Solutions Group, in a statement. "Harvesting value from all this data will be critical in separating the winners from losers. It will require cutting-edge innovation in the memory-and-storage hierarchy, which is what we are driving at Intel."

In September 2018, Intel and then-Gov. Susana Martinez announced Intel's related 3D XPoint technology development <u>would relocate to its Rio Rancho facility</u>, bringing over 100 additional jobs to the site. It has <u>since announced another 300 new jobs</u>. Those announcements helped reverse a trend of a shrinking workforce at Intel. The workforce at the Rio Rancho plant shrank by around 700 in 2016, or 37 percent. The facility <u>employed as many as 3,200 in 2013</u>.

Intel, the <u>largest manufacturer in the state</u>, hired 168 new employees at its Rio Rancho plant in 2018, up from 30 in 2017, <u>Business First reported in April</u>.

Intel plans to release the second generation of its Optane DC Persistent Memory, code-named "Barlow Pass," in 2020.

Intel's Non-Volatile Memory Solutions Group reported a net loss of \$284 million on \$940 million in revenue for the second guarter.

Along with Optane, Intel is developing its related 3D NAND technology at the Rio Rancho plant. The 3D NAND technology increases storage capacity and lowers per-gigabyte costs, offering a "cost-effective replacement for traditional hard-disk drives to help customers accelerate user experiences, improve the performance of apps and services across segments, and reduce IT costs," according to Intel.